

## Room temperature near infrared luminescence of an $U^{3+}$ doped $CsCdCl_3$ potential laser crystal.

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### Streszczenie

Good quality  $U^{3+}$  doped  $CsCdCl_3$  single crystals with a 0.05 mol%  $U^{3+}$  concentration have been obtained by the Bridgman–Stockbarger method. Luminescence spectra of the crystals were recorded at room temperature in the near infrared range. Excitation in the range of  $5f26d1$  bands at 514 nm produced a strong emission at 1.47 and 2.35  $\mu m$  from the  $4F3/2$  and  $4I11/2$  levels to the  $4I9/2$  ground level, respectively and at 3.15  $\mu m$  from the  $4F3/2$  level to the first excited component of the  $4I11/2$  level. For the first time very large lifetimes of the  $U^{3+}$  luminescence levels have been observed.

### Adres publiczny

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### Strona internetowa wydawcy

<http://www.elsevier.com>